Atomic layer deposition (ALD)

We carry out ALD processes on wafer, batch and chip level with four different ALD tools.

ALD mini (PICOSUN® R-200 std.)

- R&D of new materials
- Can be loaded manually with 200 mm wafers as well as any wafer and chip size below Ø 200 mm

ALD cluster (PICOSUN® R-200 adv.)

- Allows automatic handling and successive processing of 25 wafers of 200 mm
- Two chambers are designed respectively for thermal ALD and plasma-enhanced ALD

ALD batch (PICOSUN® P-300B)

 25 wafers of 200 mm can be processed simultaneously with homogeneous quality, aiming for a high throughput

F.A.S.T.-ALD (Plasma-Therm F.A.S.T.®)

- Four-chamber system specialized for TSV and μVia production necessary for wafer stacking
- The automatic handling of 200 mm wafers is configured to process a whole 25 wafer batch successively



ALD support for every step from precursor- and process development to pilot production.

Contact

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Technology Services

Fabrication of demonstrators and prototypes up to preproduction and pilot production.

- Automated, cassette-to-cassette equipment set up for 200 mm wafers (8")
- Area ISO4 cleanroom: >1000 m² ISO 9001 certified management system since 1995
- Digital production using modern Manufacturing Execution System (MES) by CM
- Comprehensive system for process monitoring
- Integration of wafers from external foundries
- Capacity: 4500 wafers per year
- Member of the Research Fab Microelectronics Germany (FMD)

Fraunhofer IMS

Working on a safe, secure and sustainable future with the help of Smart Sensor Systems:

Our institute consists of numerous research labs, in which we provide ASIC and chip design, CMOS, MEMS, LiDAR development services and many more microelectronic solutions. A seamless path from initial idea to development and production, while maintaining the highest quality and reliability standards, is our offer.

We look forward to giving a long-term support to our customers and be a reliable research and development partner. Fraunhofer IMS provides numerous technologies in four business units: Health, Industry, Mobility, as well as Space and Security.



Customizable photonics platform

We offer services to support your idea at all stages from first draft to pilot fabrication.

Our services include:

- Device design and simulation
- Process development
- Chip fabrication to pilot fabrication
- Device characterization
- Process transfer

Our technology platform is accessible via R&D collaborations and contracting. We are also open to collaborative projects with public funding.

Post-CMOS photonic platform

Our Post-CMOS compatible SiN-photonics platform offers low-loss components with a broad choice of device geometries and user-defined customization options.

Fraunhofer IMS platform offers silicon-nitride photonics and options for integration of new materials. Our platform uses back-end-of-line processes to enable photonics as a post-processing option on foundry wafers containing CMOS circuitry.

Based on our extensive combined experience in integrated circuits, Post-CMOS sensors and photonics, we guide you from first idea to prototype and ramp-up.

Photonics and electronics made on one manufacturing platform.



Process chain technologies

Process step	Application examples	Specification
Deposition	 Functional / sensitive layers Isolating / conductive layers Layer stack for biomedica encapsulation via ALD Temperature sensitive applications 	 CVD: SiO, SiN, Si (B, P, Ge), Ge, aSi, B, W PVD: Ti/TiN, TiW, Cu, AlSi, AlCu ICP: aSi, SiO, SiN, DLC ALD: Al₂O₃, Ta₂O₅, ZnO, AZO, TiAlCN, TiN, Ru, MoS₂, WS₂, SiO₂, Cu Thermal: SiO₂
Lithography	 Converting all necessary layers into an adequate layout Transferring alignment marks and test structures 	 0,35 µm resolution 8" Wafer Stepper 8" Mask Aligner Backside-Alignment possible Stitching
Etching	Sacrificial layer technology	 Wet chemical DRIE Ion Beam Milling / Etching Isotropic release etch (XeF2, HF) Plasma enhanced etching

Process step	Application examples	Specification
3D integration	 CMOS single photon Avalanche diodes (CSPAD) detector for light imaging, detection, and ranging (LiDAR) Electrical wafer-towafer connection through microvias 	 Wafer thinning Wafer-to-wafer-bonding Chip-to-chip-bonding Chip to wafer bonding Through Silicon Vias (TSVs) 8" Wafer
Metrology	 Scanning acoustic microscopy to detect voids at the interface between two bonded wafer 	 Void inspection Electrical wafer testing Surface profiling Sheet resistance Layer thickness, CD, and Overlay measurements Chip to wafer Through Silicon Vias (TSVs)